

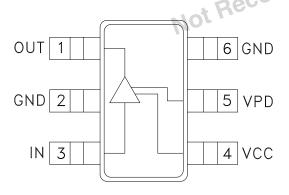
### GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 0.7 - 4.0 GHz

### Typical Applications

Ideal Broadband Gain Stage for:

- 2.2 2.7 GHz MMDS
- 3.5 GHz Wireless Local Loop
- Low Profile Portable Wireless Devices
- WLAN Systems

#### **Functional Diagram**



#### Features

single Supply: 5V Ultra Small Package: SOT26 Signs New Gen P1dB Output Power: +18 dBm

The HMC314 is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC amplifier that operates from a single positive supply. This amplifier also incorporates a power down feature. When the "Vpd" pin is held low, the amplifier will shut down. The surface mount SOT26 amplifier can be used as a broadband gain stage for wideband applications. The amplifier provides 12 dB of gain and +22 dBm of saturated power while operating from a single positive +5v supply. The HMC314 is packaged in an ultra small SOT26 package at a height of only 1.45mm.

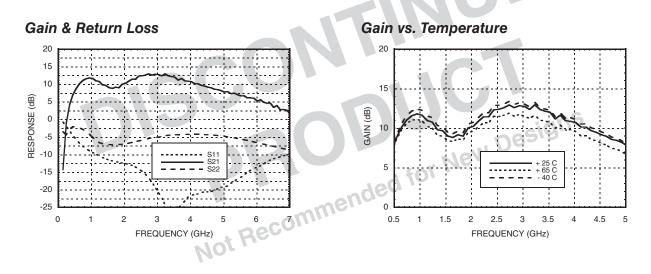
### Electrical Specifications, $T_A = +25^{\circ}$ C

Parameter -		Vs =	1 loite		
		Min.	Тур.	Max.	Units
Frequency Range		GHz			
Gain		7	12	16	dB
Gain Variation Over Temperature			0.015	0.025	dB/°C
Input Return Loss		6	12		dB
Output Return Loss		2	6		dB
Reverse Isolation		22	30		dB
Output Power for 1 dB Compression (P1dB) @ 1 GHz		15	18		dBm
Saturated Output Power (Psat) @ 1 GHz		19	22		dBm
Output Third Order Intercept (IP3) @ 1 GHz		26	29		dBm
Switching Speed	On/Off		60		ns
Supply Current (Icc)			150		mA
Control Voltage (Vpd)			0/5		Volts
Control Current (Ipd)			.001/12		mA

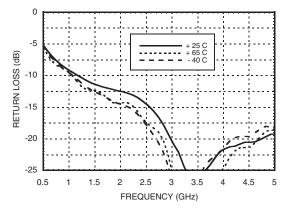
For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com



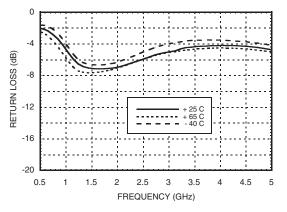
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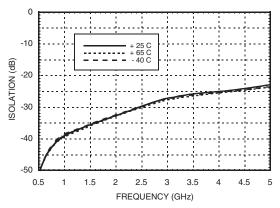
Input Return Loss vs. Temperature



**Output Return Loss vs. Temperature** 



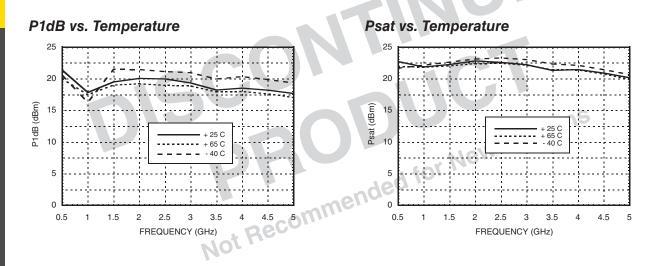




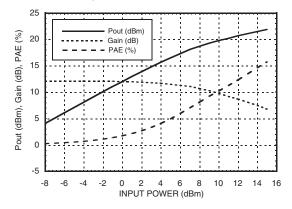
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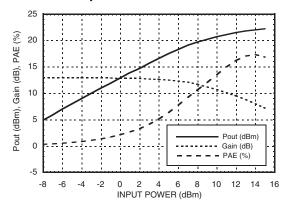
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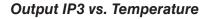


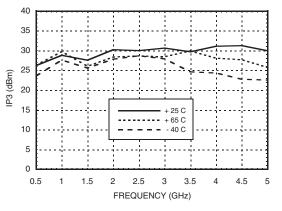
Power Compression @ 1 GHz



Power Compression @ 3 GHz







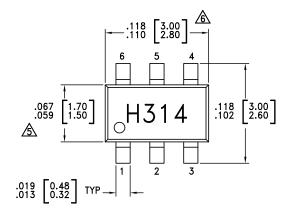
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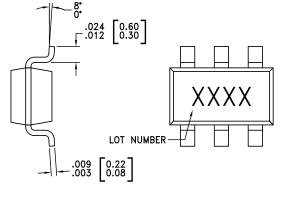


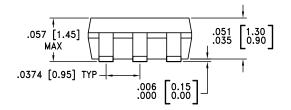
### GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 0.7 - 4.0 GHz

Absolute Maximum R	atings		Truth T	able				
Collector Bias Voltage (Vcc)	+5.0 Vdc		Vs	Vctl	ls	lctl	State	
Control Voltage Range (Vpd)	-0.2 to 3.5 Vdc		5V	5V	150 mA	12 mA	On	
RF Input Power (RFin)(Vs = +5.0 Vdc)	+20 dBm		5V	٥V	<1 µA	<1 µA	Power Down	
Junction Temperature	150 °C							
Continuous Pdiss (T = 65 °C) (derate 6.57 mW/°C above 65 °C)	0.558 W	for New Designs						
Thermal Resistance (junction to lead)	152 °C/W			- Ne	W DO			
Storage Temperature	-65 to +150 °C	ELECTROSTATIC SENSITIVE DEVICE						
Operating Temperature	-40 to +65 °C	nen					CAUTIONS	
1	-40 to +65 °C							

### **Outline Drawing**







NOTES:

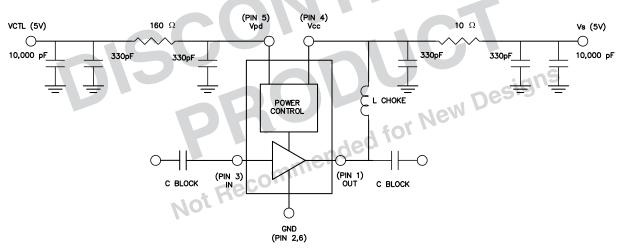
- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEADFRAME MATERIAL: COPPER ALLOY
- 3. LEADFRAME PLATING: Sn/Pb SOLDER
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
- 8. CLASSIFIED AS MOISTURE SENSITIVITY LEVEL (MSL) 1.

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### GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 0.7 - 4.0 GHz

### **Application Circuit**

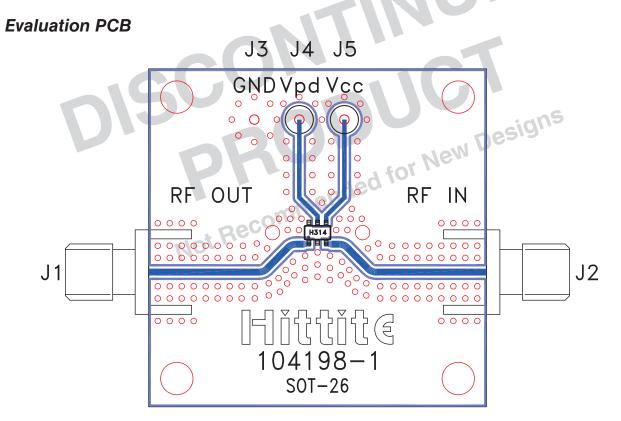


#### Note:

- 1. Requires a 10 Ohm resistor (Rbias) in series with the Vcc line and a 160 Ohm resistor in series with the Vpd line.
- 2. Requires Blocking Capacitors on Pins 1 & 3.
- 3. Requires bypass capacitors on Vcc and Vpd line as shown.



### GaAs InGaP HBT MMIC DRIVER AMPLIFIER, 0.7 - 4.0 GHz



#### List of Material

Item	Description		
J1, J2	PC Mount SMA Connector		
J3, J4, J5	DC Pins		
U1	HMC314		
PCB*	104198 Evaluation PCB 1.5" x 1.5"		
*Circuit Board Material: Roger 4350			

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.